

IFW

O I P E Docket No. TI-35853

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Initialed **PATENT** application of:

Applicant: Summerfelt, et al.

Application No.: 10/620,196

For: FERROELECTRIC MEMORY CELL WITH ANGLED CELL  
TRANSISTOR ACTIVE REGION AND METHODS FOR  
FABRICATING THE SAME

Filing Date: July 15, 2003

Examiner: Tran, Thien F.

Art Unit: 2811

**REPLY TO OFFICE ACTION DATED DECEMBER 7, 2004**

Mail Stop Amendment  
Assistant Commissioner for Patents  
Washington, D.C. 20231

Dear Sir:

Favorable reconsideration of the above-identified application is respectfully  
requested in view of the following amendment and remarks.